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Table of Contents

		Page No.
	Message from the General Chair	xiii
	Message from the Editors	xiv
1.	**Hard and Soft Switching Geometries For Operations of the MOSFET Used For the SMPS** *Tapas Halder*	1-6
2.	**Suitability of the Static Converters For the Power Factor Correction (PFC)** *Tapas Halder*	7-12
3.	**Generation of Tunable Low-noise Millimeter-wave Signal using Optical Frequency Comb through Electrical Mixing at 94 GHz** *Rajarshi Dhar, Arpan Deyasi and Angsuman Sarkar*	13-18
4.	**Swastika Shaped Broadband Dielectric Resonator Antenna for S,C,X & Ku Band** *Debjit Dey and Sukla Basu*	19-22
5.	**Study of 2D Electron Mobility in AlGaN/GaN Quantum well Structure** *Shwetapadma Panda, Kshirabdhee T. Dora, Ajit K. Panda and Trinath Sahu*	23-26
6.	**Oscillating Electron Mobility in DoubleV-shaped Quantum Well based Field Effect Transistor Structure** *Devika Jena, S. K. Palo, T. Sahu and A. K. Panda*	27-30
7.	**Analytical Investigation of Trenched Multi-layered Gate Silicon on Nothing MOSFET with Graded Work-function** *Sikha Mishra and Soumya S Mohanty*	31-35
8.	**Design and Comparative analysis of a Two-Stage Ultra-Low-Power Subthreshold Operational Amplifier in 180nm, 90nm, and 45nm technology** *Sumukh Nitundil, Nihal Singh, Rushabha Balaji and Pankaj Arora*	36-40
9.	**Impact of Source Side Cavity on Sensitivity of Hetero Channel Double Gate MOSFET Biosensor** *S. S. Mohanty, S. Mishra, M. Mohapatra and G. P. Mishra*	41-44
10.	**Investigation of TF-FinFET Based Biosensor for Early Diagnosis of Protein Carrying Diseases** *Harshal Gudaghe, Mridul Kashyap, and Rishu Chaujar*	45-49
11.	**Computing Electromagnetic Bandgap for Parallel Nanorod Structure with Double Negative Refractive Index inside Triangular Lattice**	

Rikita Das, Arpan Deyasi and Angsuman Sarkar 50-52

12. **A Comparative Investigation on Characteristics of Conventional MOSFET and Ferroelectric Thin Film Modified FET**
Rashi Mann and Rishu Chaujar 53-56

13. **Ta2O5 as Tunneling Oxide for n-type Passivated c-Si CS-TOPCon Solar Cell**
Manish Verma and Guru Prasad Mishra 57-60

14. **Linearity Performance Analysis of Hetero-dielectric Core-shell TFET**
Anju, Bibhudendra Acharya and Guru Prasad Mishra 61-64

15. **Optical XOR-XNOR logic circuits using mechanical movable mirrors**
Tanay Chattopadhyay and Dilip Kumar Gayen 65-70

16. **Analysing Structural Asymmetry on the Nonmonotonic Electron Mobility of Pseudomorphic Heterojunction Field Effect Transistors**
Sangita R. Panda, Trinath Sahu and Ajit Kumar Panda 71-74

17. **Effect of Well Width and Barrier Width on I–V Characteristics of Armchair Graphene Nanoribbon based Resonant Tunneling Diode Structure**
Madhusudan Mishra, Nikhil R. Das, Narayan Sahoo and Trinath Sahu 75-78

18. **Effect of biaxial strain on the electronic structure of Nb-doped WSe2 monolayer: a theoretical study**
Sayantika Chowdhury, P. Venkateswaran and D. Somvanshi 79-83

19. **Numerical Analysis of an Ultra-High Negative Dispersion Compensating Micro-Structured Optical Fiber With Air-holes Arranged in Octagonal Structure**
Shovasis Kumar Biswas, M. Ifaz Ahmad Isti, Mohammad Mahmudul Alam Mia, Hriteshwar Talukder and Kisalaya Chakrabarti 84-89

20. **Exhibiting Dispersive Characteristics at 1330 nm for Optical Pulse Propagation through 2D Kerr Nonlinear Medium**
Moumita Banerjee, Pampa Debnath and Arpan Deyasi 90-93

21. **Implementation of Fractional Sample Rate Digital Down Converter for Radio Receiver Applications**
Debarshi Datta, Partha Mitra and Himadri Sekhar Dutta 94-98

22. **Multisubband Electron Mobility in Pseudomorphic Al0.3Ga0.7As/In0.15Ga0.85As Double Quantum Well based FET Structure**
Narayan Sahoo, Ramchandra Swain, Ajit K. Sahu and Sangeeta K Palo 99-102

23. **Investigation of Work Function Variation on the Electrical Performance of sub-7nm GAA FETs**

E. Mohapatra, T. P. Dash, S. Das, J. Jena, J. Nanda and C. K. Maiti 103-106

24. Enhanced DC Performance of Junctionless Field-effect Transistor Using Dielectric Engineering
Mainak Maiti, Mridul Jain, Chandan Kumar Pandey 107-111

25. DG MOSFET for Bio-Sensing Applications: A Review
Namrata Mendiratta and Suman Lata Tripathi 112-115

26. A Hetero-Dielectric Double-Gate Junctionless FET with Spacer for Improved Device Performances
Mridul Jain, Mainak Maiti and Chandan Kumar Pandey 116-119

27. Impact of Channel Engineering on 16nm, 18nm & 20nm Doping-less DG MOSFET
Rupak Kumar, Suman Lata Tripathi and Manoj Singh Adhikari 120-123

28. Recessed Channel Carbon Nanotube Truncated Fin Finfet For High Performance ULSI Applications
Sanmveg Saini, Mridul Prakash Kashyap and Rishu Chaujar 124-128

29. Novel SPICE Model for bifacial solar cell to increase the renewable power generation
Kholee Phimu, Khomdram Jolson Singh and Rudra Sankar Dhar 129-133

30. Body Connection Assessment of MOS-Diodes for MOS-Quadrupler based RF Energy Harvesting Circuit
Chandra Prakash Singh, Saurabh Kumar Pandey and Jawar Singh 134-138

31. Capacitive Analysis of Strained Superjunction Vertical Single Diffused MOSFET
Onika Parmar, Payal Nautiyal and Alok Naugarhiya 139-142

32. Performance Analysis of FinFET based inverter at 7nm Technology Node Using TCAD Simulation
J. Jena, S. Das, E. Mohapatra, J. Nanda and T. P. Dash 143-147

33. Computational analysis of doped (10, 0) MoS2 ANR metal junction by Schottky Barrier height modulation
Lopamudra Banerjee and Hafizur Rahaman 148-151

34. Influence of High-k Dielectrics on Nanowire FETs
Rajiv Ranjan Thakur and Nidhi Chaturvedi 152-155

35. Nanocomposites based Solid State Electrochromic Nano-Material Membrane Device
Silpee Talukdar, Rudra Sankar Dhar, Raghvendra Singh and Lipa Roy 156-160

36. Autonomous Remote - monitoring Low – cost Agricultural System

Udayan Bhattacharyya, Debanjan Mandal, Nikita Agarwal, Sayantika Sanyal, Sohom Basak, Shnouli Mukherjee, Anisha Karmakar, Saurav Sarkar and Basumita Roychowdhury 161-165

37. Power Supply Noise Aware Physical Design with Decoupling Capacitance Allocation in System-on-Chip
Partha Mitra, Jaydeb Bhaumik and Angsuman Sarkar 166-169

38. A Low Voltage Rectifier for Piezo-Electric Energy Harvesting Designed in CMOS Technology
Antaryami Panigrahi, Sanjay Sarania and Rafwd Gwra Brahma 170-174

39. A Design of Frequency Encoded Dibit-based Comparator Using Reflective Semiconductor Optical Amplifier with Simulative Verification
Surajit Bosu and Baibaswata Bhattacharjee 175-179

40. Power Optimized 10 Bit ADC IP Design in Transistor Level
Kaushik Mazumdar and Ananya Ghorai 180-184

41. A non-iterative hybrid Dynamic State Estimation scheme utilizing PMU and SCADA measurements
S. Kundu, M. Alam, B. K. Saha Roy and S. S. Thakur 185-189

42. Modelling and Simulation of GaAs Nanowire Transistors
Kaushik Mazumdar and Vikas Patel 190-192

43. Influence of High-k Oxide Thickness on Gate Stack DMG Junctionless SOI MOSFET
Ankush Chattopadhyay, Mrinmoy Goswami and Chayanika Bose 193-197

44. Temperature associated reliability analysis of a Si/Ge Heterojunction Dopingless Tunnel FET considering Interface Trap Charges
Suruchi Sharma, Rikmantra Basu and Baljit Kaur 198-203

45. Novel 9:1 Ternary Multiplexer on 32nm CMOS Technology
Rahul Pal, Rakesh Kumar Singh, Jayanta Ghosh and Aloke Saha 204-207

46. DC Exploration of Oxide Trap Charge Effects on Electrically Doped Nano Ribbon FET
Annada Shankar Lenka, Prasanna Kumar Sahu and Sayan Bagchi 208-210

47. Robust Design of Noise Tolerant 2-Phase Non Overlapping Clock Generating Circuit
Saianudeep Reddy Nayini, Krishna Sai Kushal Gella, Shashank Kumar Dubey, Manisha Guduri and Aminul Islam 211-215

48. AlGaN/GaN HEMT with Recessed T-Gate and Floating Metal for High Power Applications

Shashank Kumar Dubey and Aminul Islam 216-220

49. An ab-initio study of 2 dimensional metal (Cu, Ag) -1T' ReS2 van der Waals heterostructure
Amretashis Sengupta 221-223

50. TCAD Analysis and Simulation of Double Metal Negative Capacitance FET (DM NCFET)
Yash Pathak, Bansi Dhar Malhotra and Rishu Chaujar 224-228

51. Impact of Ferroelectric Oxide Layer on Palladium Silicide Source Electrode based Double-Gate Junctionless TFET
Preeti Sharma, Jaya Madan, Rahul Pandey and Rajnish Sharma 229-232

52. Nanowire texturisation of Multi Crystalline Silicon using Silver Assisted Chemical Etching
Sangeeta Barua, Sikha Bandyopadhyay, Ashok Kumar Mondal and Sayan Chatterjee 233-237

53. Magnesium Silicide Source Double Palladium Metal Gate TFET for Highly Sensitive Hydrogen Gas Sensor
Minaxi Dassi, Jaya Madan, Rahul Pandey and Rajnish Sharma 238-241

54. Analysis of Static Noise Margin of 10T SRAM Using Sleepy Stack Transistor Approach
Umakanta Nanda, Debasish Nayak, Suraj Kumar Saw, Abdul Majeed K K and Biswajit Jena 242-246

55. Band Offset Dependent Performance Analysis of SnO/mc-Si Heterojunction Solar Cell
Lipika Mandal, Syed Sadique Anwer Askari, Md Aref Billaha and Manoj Kumar 247-250

56. Temperature Variation Analysis of SiGe Source based Heterojunction Tunnel FETs
Irfan Pindoo and Sanjeet K Sinha 251-255

57. Validation of Input/Output characteristics of Symmetrical Double Source TFET device
Bijoy Goswami, Savio Sengupta, Wasim Reja, Pritam Das and Subir Kumar Sarkar 256-259

58. Trapezoidal Channel Double Gate Tunnel FET Suitable for better Scalability, Speed and Low Power Application
Bijoy Goswami, Pritam Das, Abhishek Dey, Savio Sengupta and Subir Kumar Sarkar 260-265

59. Study on Junction Temperature Management of White pcLED at High Ambient Temperature in Industrial Environment: An Indian Perspective
H Bhattacharjee, A Chakraborty, R Ganguly and M. Mitra 266-269

60. Work-Function Modulated GAA MOSFET for Improved Electrostatic Controllability in Lower Technology Node

Krutideepa Bhol, Biswajit Jena,Umakanta Nanda and Shubham Tayal 270-274

61. HeartHealth: An Intelligent Model for Multi-Attribute Based Heart Condition Monitoring using Fuzzy-TOPSIS Method
Amiya Karmakar, Kaustabh Ganguly and Partha Sarathi Banerjee 275-279

62. Performance Evolution of the GaAs1-xSbx FinFET for the Mole Fraction Variation
Ankit Dixit, Dip Prakash Samajdar and Navjeet Bagga 280-283

63. SIC-TPG for path delay fault detection in VLSI circuits using scan insertion method
Sabir Hussain, M A Raheem and Afaq Ahmed 284-288

64. Simulation and Performance Analysis of novel InNGaN-BTG-MOSFET
Pranav Tripathi and Rishu Chaujar 289-292

65. Lower Fin Modulation Analysis for a Novel 5nm Top Bottom Gated Junctionless FinFET for improved performance
Lakshya Gangwani, Ruchika Chakravarti and Rishu Chaujar 293-297

66. Asymmetric Gate Stack Triple Metal Gate All Around MOSFET (AGSTM) for Improved Analog Applications
Arvind Ganesh, Jaskeerat Singh Mayall, Kshitij Goel and Sonam Rewari 298-302

67. Multiband Fano Resonance in Symmetry Broken Planar Terahertz Metamaterial
K.A.Karthigeyan, E.Manikandan, E Papanasam, S.Radha, B.S.Sreeja 303-305

68. Analog Performance of Dual- Metal Gate Stack Architecture of Junctionless Accumulation-Mode Cylindrical Surrounding Gate (DMGSA-JAM-CSG) MOSFET
Sumedha Gupta, Neeta Pandey and R S Gupta 306-310

69. Design of a Modified 8-bit Semiflash Analog to Digital Converter
Pranati Ghoshal, Chanchal Dey and Sunit Kumar Sen 311-315

70. Impact of Channel Splitting on Gate All Around Tunnel Field Effect Transistor (GAATFET)
Mayuresh Joshi, Arya Dutt, Sanjana Tiwari, Prakhar Nigam, Ankur Beohar and Ribu Mathew 316-320

71. Simple and easy one step method for synthesizing ZnO nanorods for high frequency device application
Gyanendra Pratap Singh and Mukesh Kumar Roy 321-324

72. Solar Powered Home Automation System Enhanced with Internet of Things and Network Time Protocol Server

Chiradeep Ghosh, Somdeb Chanda and Himadri Shekhar Dutta 325-329

73. Symmetrical and Asymmetrical Fault Studies of Wind-Farm Embedded Power Network
S. Maiti, S. Som, S. Mondal and P. K. Gayen 330-334

74. Complementary Memresistive Switch Based Realization of Delay and Toggle Flip-Flop
Pooja Joshi and Hafizur Rahaman 335-339

75. Serial and Parallel based Intrusion Detection System using Machine Learning
Indrajit Das, Shalini Singh and Ayantika Sarkar 340-344

76. L-shaped piezoelectric energy harvester for low frequency application
Ashuntosh Anand, Geetanjali Singh, Abhishek Pandey, Srikanta Pal and Sudip Kundu 345-349

77. Study on Power Quality Phenomena of Grid connected AC Micro-grid
S. Pramanick, N. Konar, S. Dey, S. Som and P. K. Gayen 350-354

78. Strained SiGe Channel TFTs For Flexible Electronics Applications
T. P. Dash, E. Mohapatra, S. Choudhury, B. Jena and C. K. Maiti 355-358

79. Parametric Analysis for Varied Gate Work function in Trigate n-channel FinFET
Ayush Shrivastava, Swagat Nanda, Serto Engneichung Aimol and Rudra Sankar Dhar 359-362

80. Linearity Investigation of Ultra-Low-Power Cylindrical SOI Schottky Barrier MOSFET for Biomedical and 5G/LTE Circuits Application
Amit Saxena, R. K Sharma, Manoj Kumar and R. S Gupta 363-367

81. Generalized Memristor Model using Simulink and its Rectification for Sinusoidal and other Periodic Signals
Panthadeb Saha, Rudra Nath Palit and Prasun Ghosal 368-372

82. Gate - Stack Dual Metal (DM) Nanowire FET with Enhanced Analog Performance for High Frequency Applications
Neeraj, Shobha Sharma, Anubha Goel, Sonam Rewari and R. S. Gupta 373-377

83. An Area Efficient VLSI Architecture for 1-D and 2-D Discrete Wavelet Transform (DWT) and Inverse Discrete Wavelet Transform (IDWT)
Jhilam Jana, Sayan Tripathi, Ritesh Sur Chowdhury, Akash Bhattacharya and Jaydeb Bhaumik 378-382

84. Efficient rectifier for piezoelectric energy harvester using active diode
Geetanjali Singh, Srikanta Pal and Sudip Kundu 383-387

85. All-Optical Frequency Encoded Dibit-based Half Adder using Reflective Semiconductor Optical Amplifier with Simulative

Verification

Surajit Bosu and Baibaswata Bhattacharjee 388-392

86. Numerical Simulation of GaN-BTG MOSFET for Suppression of SCEs

Shreya Sahu, M M Tripathi and Ajay Kumar 393-396

87. Features of Snapback in Compact Memory Devices For High Performance Integrated Circuits

Pragati Singh, Rudra Sankar Dhar and Srimanta Baishya 397-400

88. Minimizing Wirelength with Bend Reduction using Gradient Descent PSO Hybrid in VLSI Global Routing

Subhrapratim Nath, Aditya Shankar, Ritankar Sarkar, Suharta Banerjee, Jamuna Kanta Sing and Subir Kumar Sarkar 401-405

89. Technology Computer Aided Design of a Novel Fully Gate Covered Channel Junctionless SOI FinFET for high performance analog applications

Gaurav Mangal, Aman Tyagi and Rishu Chaujar 406-410

90. A Simulation Study of 2-D Electron Gas in GaN HEMT for High-Speed Applications

Devika Jena, E. Mohapatra, F. A. Ali and T. P. Dash 411-415

91. Investigation of III-V Tunnel FETs for Analog Circuit Design

Atul Kumar Yadav and Abhishek Acharya 416-420

92. Analysis of Dual Metal Gate Engineered SiGe/Si TFET based Biosensor: A Dielectric Modulation Approach

Dipanjan Sen, Priyanka Saha and Subir Kumar Sarkar 421-424

93. FPGA Implementation of an Image Watermarking Scheme based on Intensity Level Matching

Subhrajit Sinha Roy, Abhishek Basu and Avik Chattopadhyay 425-429

94. In-memory Computing based Boolean and logical Circuit Design using 8T SRAM

Chakka Yeswanth and Abhishek Acharya 430-434

95. Impact of Au and Ag contact on the electrical parameters of MnO2 Nanowires grown by Glancing Angle Deposition technique

Stacy A Lynrah and P Chinnamuthu 435-437

96. Design and Analysis of III-V Tunnel FET based Energy Efficient Digital Circuits

Manisha Mogili and Abhishek Aacharya 438-445

97. **Design and Performance Analysis of Z-Shaped Charge Plasma TFET-based label-free Biosensor**
Shivangi Gupta, Anju and Guru Prasad Mishra 446-449

98. **Neural network based soft sensor for critical parameter estimation of gas turbine engine**
V. Prabakar 450-454

99. **Simulation of Low Power DVCC Based LNA for Wireless Receiver**
Malika Jain and Ramesh Bharti 455-460

100. **Exploration of 9T SRAM Cell for In Memory Computing Application**
Aman Kumar Gupta and Abhishek Acharya 461-465

101. **The Performance Analysis of 70nm T-gate InAlN/AlN MOS-HEMT using Graded Buffer**
Megha Sharma and Rishu Chaujar 466-470

102. **Stress-Engineered AlGaN/GaN High Electron Mobility Transistors Design**
S. Das, E. Mohapatra, S. Choudhury, T. P. Dash and C. K. Maiti 471-473

103. **Harmonic Suppression in a Folded Hairpin-Line Cross-Coupled Bandpass Filter by using Spur-Line**
Tarun Kumar Das and Sayan Chatterjee 474-478

104. **A Novel Junction Less Dual Gate Tunnel FET with SiGe Pocket for Low Power Applications**
Sabitabrata Bhattacharya and Suman Lata Tripathi 479-483

105. **A Dielectric Modulated MOS transistor for Biosensing**
Gargi Jana, Papiya Debnath and Manash Chanda 484-488

106. **A Review on Machine Learning Approaches for Predicting the Effect of Device Parameters on Performance of Nanoscale MOSFETs**
Rachita Ghoshhajra, Kalyan Biswas and Angsuman Sarkar 489-493

107. **Study of Lead-Free Perovskite and Quantum Dots Core-Shell Infrared Photodetector Integrated with the Silicon Technology**
Mariya Aleksandrova 494-497

108. **A 0.6 V 1.6 nA Constant Current Reference Circuit with Improved Power Supply Sensitivity**
Taha Saquib, Saheli Sarkhel and Soumya Pandit 498-503

109. **Variation of Rain Rate Effects for Terrestrial Communication at Frequencies above 10 GHz**
Dalia Nandi and Sandip Nandi 504-507

110. A 2.24 NEF Current-Balancing Instrumentation Amplifier Using Inverter-Based Transimpedance Stage for ECG Signal Acquisition in 180nm Technology

Justine Lewis Silvestre 508-511

111. Radiation-Hardened Low Read Delay 12TSRAM Cell for Space Applications

Jyothi Prakash Kotni, Monalisa Pandey, Santrashraya Prasad and Aminul Islam 512-516

112. Effect of Drain Engineering on DC and RF Characteristics in Ge-source SD-ZHP-TFET

Rajesh Saha, Deepak Panda, Rupam Goswami, Brinda Bhowmick and Srimanta Baishya 517-520

113. Performance Analysis of Full Adder Circuits Using Different Static CMOS Based Threshold Logic Gate

Mili Sarkar and Gouranga Sundar Taki 521-524

114. Double Gate-Pocket-Junction-less Tunnel Field Effect Transistor

Isukapalli Vishnu Vardhan Reddy and Suman Lata Tripathi 525-527

115. AN INTELLIGENT WEATHER PREDICTION SYSTEM BASED ON IOT

Mrinmoy Sadhukhan, Sudakshina Dasgupta and Indrajit Bhattacharya 528-532

116. GaN-Based Two-Stage Colpitts Oscillator for Wireless Power Transfer

Anwar Jarndal, Khalid Kamel and Ahmed S. Elwakil 533-535

117. Authentication and secure communication by Haar Cascade Classifier , Eigen Face , LBP Histogram and variable irreducible polynomial in (28) finite field

Indrajit Das, Ayantika Sarkar, Shalini Singh and Sunil Kumar Sawant 536-540

118. Impact of temperature and different types of trap charges on noise behavior of Non-uniform Body with Dual Material Source TFET (NUTFETDMS)

Jagritee Talukdar and Kavicharan Mummaneni 541-544

119. Analysis of Double-Gate Junctionless MOSFET for Energy Efficient Digital Application

Adrija Mukherjee, Deepro Banerjee, Tanushree Ganguli, and Angsuman Sarkar 545-549

120. Hardware realization and testing of multistage OTA buffer amplifier for heavy resistive load

Remya Jayachandran, K J Dhanaraj and P C Subramaniam 550-554

121. Design of Duty-Ratio and Phase-Shift Control Circuits for MPPT of SPV Source using ZV-ZCS PSFB Converters

Sarbojit Mukherjee, Shib Sankar Saha and Sumana Chowdhury 555-559

122. Power Dissipation Estimation in SWCNT based Interconnects

Sobhit Saxena, Suman Lata Tripathi and Vikram Kumar Kamboj 560-563

123. Highly Linearized GaN HEMT Based Class E/F3 Power Amplifier

Gaurav Bhargava and Shubhankar Majumdar 564-568

124. A 1.8V 5-bit Segmented Current Steering Digital-to-Analog Converter

Sneha Patel and Usha Mehta 569-571

125. A Framework for Post Disaster Management using Device to Device Communication with Controlled Mobility and Opportunistic Routing

Ritwik Mondal, Ananya Biswas, Indrajit Bhattacharya and Priya Ranjan Sinha Mahapatra 572-576

126. The impact of oxide layer width variation on the performance parameters of FinFET

Dhananjaya Tripathy, Prakash Kumar Rout, Debasish Nayak, Sudhanshu Mohan Biswal and Nalini Singh 577-580

127. Highly Efficient and Compact Silicon based Novel Michelson Interferometer Modulator

Mursal Hamdani and Gausia Qazi 581-585

128. Performance Analysis of Single Operational Transresistance Amplifier Based Bandpass Filter and Bandreject Filter

Subhasish Banerjee, Pulak Mondal and Mourina Ghosh 586-590

129. Impact of Ge Grading Profile on the Performance Characteristics of SiGe Heterojunction Bipolar Transistors

M. R. Jena, A. K. Panda and G. N. Dash 591-596

130. Parametric Study of Silicon-Based Tubular Tunnel FET for Biosensing Application

Avtar Singh, Gangiregula Subbarao, Ashenafi Fekadu Shifaw and Dereje Tekilu 597-600

131. Study of SiGe-Si Source Stacked in Silicon Nano-Tube Tunnel FET

Avtar Singh and Viranjay Mohan Srivastava 601-604

132. Metaheuristic algorithms-based approach for optimal design of improvised fully differential amplifier for biomedical applications

Swagata Devi, Koushik Guha and Krishna Baishnab 605-609

133. Energy Efficient Decoder Circuit Using Source Biasing Technique in CNTFET Technology

Chandra Shaker Pittala, M. Lavanya, V. Vijay, Y. V. J. C. Reddy, S. China Venkateswarlu and Rajeev Ratna Vallabhuni 610-615

134. Comparative study on Analog & RF Parameter of InAlN/AlN/GaN Normally off HEMTs with and without AlGaN Back Barrier
Nisarga Chand, Sanjit Kumar Swain, Sudhanshu Mohan Biswal, Angsuman Sarkar and Sarosij Adak 616-620

135. An SOI n-p-n Double Gate TFET for Low Power Applications
Deepjyoti Deb, Rupam Goswami, Ratul Baruah, Kavindra Kandpal and Rajesh Saha 621-623

136. Design Approach for Parameter Estimators for One-parameter First-order Scalar Plant
Arnab Das, Bipa Datta and Achintya Das 624-628

137. Ultra Low-Power Low-Pass Filter Design for Wearable Biomedical Applications
Diksha Thakur, Kulbhushan Sharma and Rajnish Sharma 629-632

138. Optimization of Mixed Sn and Pb Perovskite Solar Cell in Terms of Transport Layers and Absorber Layer Thickness Variation
Sakshi Sharma, Rahul Pandey, Jaya Madan and Rajnish Sharma 633-636

139. A Low Voltage NMOS current bleeding down conversion Mixer with source degeneration in 0.18µm CMOS Technology
M. A. Raheem and M. Mohamed Sabir Hussain 637-642

140. DFT Based approach to sense SF6 decomposed gases (SO2, SOF2, SO2F2) using Ni doped WS2 monolayer
Suman Sarkar, Papiya Debnath, *Manash Chanda and Debashis De* 643-647

141. Analytical Model For Tunnel Current Through 1D Channel in Advanced nano MOSFET
Rathin Basak, Biswajit Maiti and Abhijit Mallik 648-651

142. Analysis of electrical properties of unpolarized/polarized CNT-BNNT-CNT for varying lengths of BNNT
Indra Kumar Nepal, Chenga Tshering Bhutia, Abinash Thapa, Bibek Chettri, Sanat Kumar Das and Bikash Sharma 652-654

143. First Principle Study of MoS2 adsorbed Transition Metal for Sensing Urea and Methanol
Priyanka Sharma, Milimmit Lepcha, Bibek Chettri, Abinash Thapa, Pronita Chettri and Bikash Sharma 655-658

144. First Principle Study of MoS2 adsorbed Transition Metal for Sensing NH3 and CH4
Prasanna Karki, Bibek Chettri, Abinash Thapa, Pronita Chettri and Bikash Sharma 659-661